

# 70T651S10BFI

### 70T651S10BFI Information

	 70T651S10BFI IDT, Integrated Device Technology Inc Integrated Circuits (ICs) Memory IC SRAM 9MBIT 10NS 208CABGA 208-LFBGA For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

E-mail: salesdept@heisener.com

# For Reference Only

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# 70T651S10BFI Specifications

Manufacturer Part Number	70T651S10BFI
Manufacturer	IDT, Integrated Device Technology Inc
Category	Integrated Circuits (ICs)
	Memory
Package	208-LFBGA
Series	-
Memory Type	Volatile
Memory Format	SRAM
Technology	SRAM - Dual Port, Asynchronous
Memory Size	9Mb (256K x 36)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	10ns
Access Time	10ns
Voltage - Supply	2.4 V ~ 2.6 V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	208-LFBGA
Supplier Device Package	208-CABGA (15x15)
	Report errors?

#### 70T651S10BFI Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE UARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### 70T651S10BFI Payment Methods





If you have any question about 70T651S10BFI, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com